#### 1<sub>1</sub>0 № Ц 19 CLK1 СГКО 🛛 З 18 CLK1# СLК0# 🛛 4 17 GND M\_reset 5 PLL\_ByPass 6 15 IN\_SEL 14 Ref\_IN NC 7 13 XTAL\_IN VDDA 🛛 8 12 XTAL\_OUT N\_SEL0 0 9 11 N\_SEL1

#### **Pin Configuration - TSSOP**

# **Pinout Table - TSSOP**

Pin No.	Pin Name	І/О Туре		Description
1,7	NC			No connection
2, 20	VDDO	Power	-	Output Power Supply
3,4	CLK0, CLK0#	Output	-	LVPECL Output clock 0
5	M_reset	Input	Pull-down	Master reset. "1", CLK0/CLK1 go to "low", CLK0#/CLK1# go to "high"; "0" outputs are enabled
6	PLL_ByPass	Input	Pull-down	PLL bypass select. "0" PLL is enabled, "1" PLL is bypassed
8	VDDA	Power	-	Analog Power Supply
9, 11	N_SEL0, N_SEL1	Input	Pull-down	Output frequency select
10, 16	VDD	Power	-	Core Power Supply
12, 13	XTAL_OUT, XTAL_IN	Crystal	-	Crystal input and output
14	Ref_IN	Input	Pull-down	CMOS reference clock input
15	IN_SEL	Input	Pull-down	"0" selects Crystal, "1" selects reference input
17	GND	Ground	-	Ground
18, 19	CLK1#, CLK1	Output	-	LVPECL Output clock 1

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# **Output Frequency Selection Table**

Xtal Frequency (MHz)	N_SEL1 N_SEL0	Output Frequency (MHz)
	00	156.25
25	01	125
25	10	62.5
	11	125

### **Typical Crystal Requirement**

Parameter	Minimum	Typical	Maximum	Units
Mode of Oscillation		Fundamental		
Frequency	22.4	25	27.2	MHz
Equivalent Series Resistance (ESR)			50	Ω
Shunt Capacitance			7	pF
Drive Level			1	mW

# **Recommended Crystal Specification**

Pericom recommends:

- a) FL2500047, SMD 3.2x2.5(4P), 25MHz, CL=18pF, +/-20ppm, http://www.pericom.com/pdf/datasheets/se/FL.pdf
- b) FY2500091, SMD 5x3.2(4P), 25MHz, CL=18pF, +/-30ppm, http://www.pericom.com/pdf/datasheets/se/FY\_F9.pdf

#### Maximum Ratings (Over operating free-air temperature range)

Storage Temperature65°C to+155°C
Ambient Temperature with Power Applied40°C to+85°C
3.3V Supply Voltage0.5 to +3.7V
ESD Protection (HBM) 2000V

#### Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

# **DC Electrical Characteristics**

**Power Supply DC Characterisitcs,**  $(T_A = -40^{\circ}C \text{ to } 85^{\circ}C)$ 

Symbol	Parameter	Condition	Min	Тур	Max	Units
V <sub>DD</sub> , V <sub>DDA</sub> , V <sub>DDO</sub>	Supply Voltage		2.97	3.3	3.63	V
V <sub>DD,</sub> V <sub>DDA</sub> , V <sub>DDO</sub>	Supply Voltage		2.375	2.5	2.625	V
I <sub>GND</sub>	Power Supply Current				110	mA
I <sub>DDA</sub>	Analog Supply Current				26	mA

#### **LVCMOS/LVTTL DC Characterisitcs,** $(T_A = -40 \text{ °C to } 85 \text{ °C})$

Symbol	Parameter	Condition	Min	Тур	Max	Units
	Louist II: -h Maltana	$V_{\rm DD} = 3.3 \ { m V}$ +/- 10%	2		V <sub>DD</sub> + 0.3	V
V <sub>IH</sub>	Input High Voltage	$V_{\rm DD}$ = 2.5 V +/- 5%	1.7		V <sub>DD</sub> + 0.3	V
V <sub>IL</sub> I	Input Low Voltage	$V_{DD} = 3.3 \text{ V} + 10\%$	-0.3		0.8	V
	Input Low Voltage	$V_{DD} = 2.5 \text{ V} + -5\%$	-0.3		0.7	V
I <sub>IH</sub>	Input High Current	M_reset, PLL_ByPass, N_SEL[0:1], IN_SEL, Ref_IN V <sub>DD</sub> = VIN = 3.63V			150	μΑ
I <sub>IL</sub>	Input Low Current	$M\_reset, PLL\_ByPass, N\_SEL[0:1],$ $IN\_SEL, Ref\_IN$ $V_{DD} = 3.63V, V_{IN} = 0V$	-5			μΑ

#### **Pin Characterisitcs**

Symbol	Parameter	Condition	Min	Тур	Max	Units
C <sub>IN</sub>	Input Capacitance			4		pF
R <sub>PULLDOWNN</sub>	Pull down resistor			51		kΩ

Symbol	Parameter	Condition	Min	Тур	Max	Units
V <sub>OH</sub> Output High Voltage <sup>(1)</sup>	$V_{\rm DD} = 3.3 V$	1.9		2.4	3.7	
		$V_{DD} = 2.5 V$	1.1		1.6	V
V <sub>OL</sub> Output Low	Output Low Voltogo(1)	$V_{\rm DD} = 3.3 V$	1.2		1.6	v
	Output Low Voltage <sup>(1)</sup>	V <sub>DD</sub> = 2.5V	0.4		0.8	

#### **LVPECL DC Characterisitcs,** $(T_A = -40 \circ C \text{ to } 85 \circ C)$

Note: 1. LVPECL Termination: Source 150ohm to GND and 100ohm across CLK and CLK#.

#### AC Electrical Characteristics, $(T_A = -40 \circ C \text{ to } 85 \circ C)$

LVPECL Termination: Source 1500hm to GND and using 0.01uF ac-coupled to 500hm to GND

Symbol	Parameter	Condition	Min.	Тур.	Max	Units
		N_SEL[1:0] = 00	140		170	MHz
fout	Output Frequency	N_SEL[1:0] = 01, 11	112		136	MHz
		$N_{SEL}[1:0] = 10$	56		68	MHz
t <sub>sk(o)</sub>	Output Skew <sup>(1, 3)</sup>	Outputs with the same loading			70	ps
		156.25MHz, (1.875MHz - 20MHz)		0.14		ps
	RMS Phase Jitter, (Random) <sup>(2)</sup>	156.25MHz, (12kHz - 20MHz)		0.3		ps
		125MHz, (1.875MHz - 20MHz)		0.13		ps
t <sub>jit(Ø)</sub>		125MHz, (12kHz - 20MHz)		0.28		ps
		62.5MHz, (1.875MHz - 20MHz)		0.25		ps
		62.5MHz, (12kHz - 20MHz)		0.36		ps
t <sub>R</sub> / t <sub>F</sub>	Output Rise/Fall Time	20% to 80%			400	ps
odc	Output Duty Cycle		48		52	%

Note:

1. Defined as skew within a bank of outputs at the same supply voltage and with equal load conditions. Measured at the differential cross points.

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2. Please refer to the Phase Noise Plots.

3. This parameter is defined in accordance with JEDEC Standard 65.

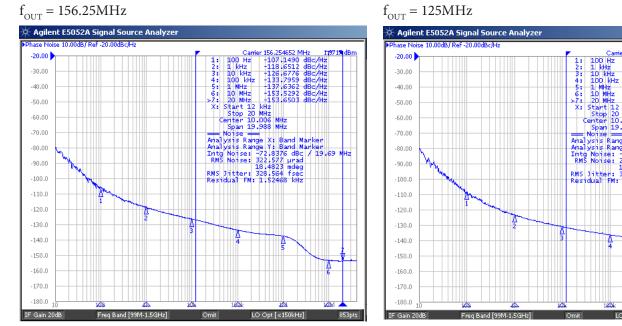
2.182<del>8 d</del>Br

ker 19.99 MHz

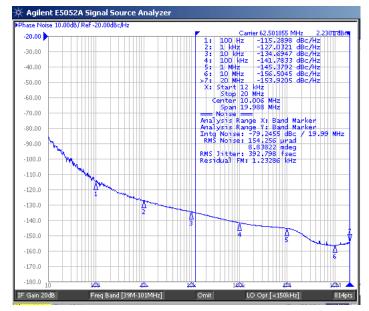
8140

125.003677 ... -108.4606 -123.2922 -131.2541 -136.5203 -139.5813 -155.7612 -1978

### **Phase Noise Plots**

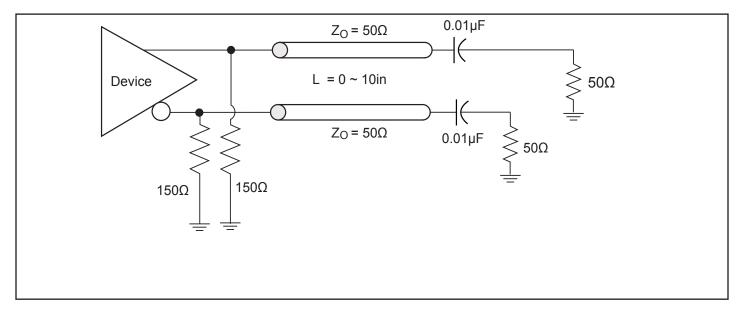


#### $f_{OUT} = 62.5 MHz$



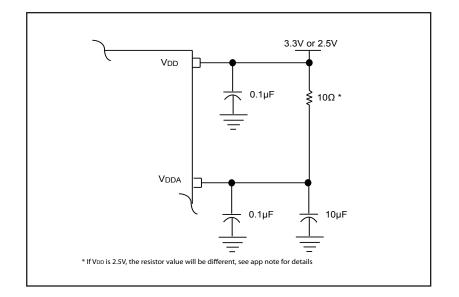


## **LVPECL** Test Circuit



# **Power Supply Filtering Techniques**

As in any high speed analog circuitry, the power supply pins are vulnerable to random noise. To achieve optimum jitter performance, power supply isolation is required. The PI6LC48P0201 provides separate power supplies to isolate any high switching noise from the outputs to the internal PLL.  $V_{DD}$ ,  $V_{DDA}$  and  $V_{DDO}$  should be individually connected to the power supply plane through vias, and  $0.1\mu$ F bypass capacitors should be used for each pin. Figure below illustrates this for a generic  $V_{DD}$  pin and also shows that  $V_{DDA}$  requires that an additional 10 $\Omega$  resistor along with a 10 $\mu$ F bypass capacitor be connected to the  $V_{DDA}$  pin.



### **Recommendations for Unused Input and Output Pins**

Inputs:

#### Crystal Inputs:

For applications not requiring the use of the crystal oscillator input, both XTAL\_IN and XTAL\_OUT can be left floating. A  $1k\Omega$  resistor can be tied from XTAL\_IN to ground for additional protection.

#### Ref\_IN Input:

For applications not requiring the use of the clock, it can be left floating. A  $1k\Omega$  resistor tied from the Ref\_IN to ground can provide additional protection.

#### LVCMOS Control Pins:

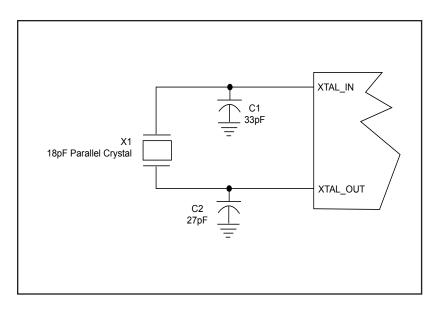
All control pins have internal pulldowns; A  $1k\Omega$  resistor tied from each control pin to ground can provide additional protection.

#### **Outputs:**

LVPECL Outputs: All unused LVPECL outputs can be left floating.

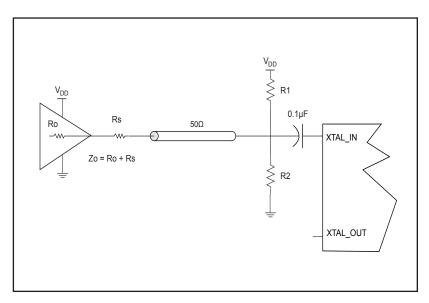
# **Crystal Input Interface**

The clock generator has been characterized with 18pF parallel resonant crystals. The capacitor values shown in the figure below were determined using a 25MHz, 18pF parallel resonant crystal and were chosen to minimize the ppm error.



# **LVCMOS to XTAL Interface**

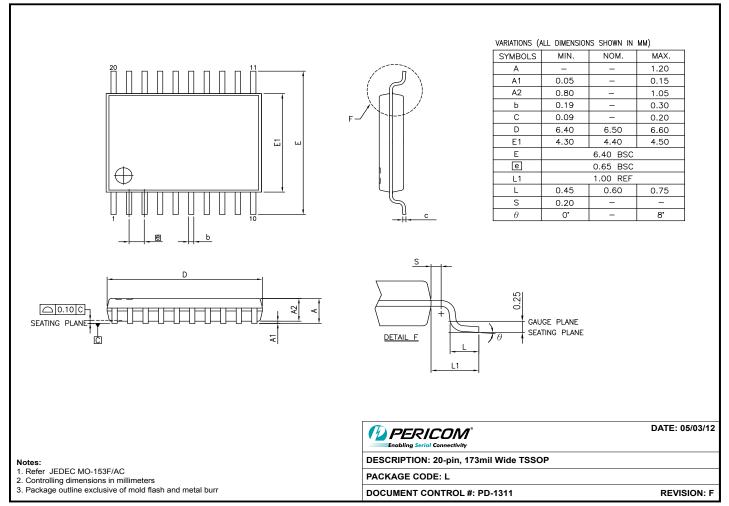
The XTAL\_IN input can accept a single-ended LVCMOS signal through an AC coupling capacitor. A general interface diagram is shown in the figure below. The XTAL\_OUT pin can be left floating. The input edge rate can be as slow as 10ns. For LVCMOS signals, it is recommended that the amplitude be reduced from full swing to half swing in order to prevent signal interference with the power rail and to reduce noise. This configuration requires that the output impedance of the driver (Ro) plus the series resistance (Rs) equals the transmission line impedance. In addition, matched termination at the crystal input will attenuate the signal in half. This can be done in one of the two ways. First, R1 and R2 in parallel should equal the transmission line empedance. For most  $50\Omega$  applications, R1 and R2 can be  $100\Omega$ . This can also be accomplished by removing R1 and making R2  $50\Omega$ . By overdriving the crystal oscillator, the device will be functional, but note, the device performance is quaranteed by using a quartz crystal.



# **Thermal Information**

Symbol	Description	
$\Theta_{_{JA}}$	Junction-to-ambient thermal resistance	84.0 °C/W
$\Theta_{\rm JC}$	Junction-to-case thermal resistance	17.0 °C/W

# Packaging Mechanical: 20-Contact TSSOP (L)



12-0373

### **Ordering Information**

Ordering Code	Packaging Type	Package Description	Operating Temperature
PI6LC48P0201LIE	L	Pb-free & Green, 20-pin TSSOP	Industrial
PI6LC48P0201LIEX	L	Pb-free & Green, 20-pin TSSOP, Tape & Reel	Industrial

Notes:

- Thermal characteristics can be found on the company web site at www.pericom.com/packaging/
- "E" denotes Pb-free and Green
- Adding an "X" at the end of the ordering code denotes tape and reel packaging

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